



Center for Energy Efficient
Electronics Science

Theme 2: Nanomechanics



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Professors: Farnaz Niroui, Jeffrey Lang, Vladimir Bulović,
Jing Kong, Timothy Swager



Students: Aldo Vidaña, Edgar Acosta, Robert Sifuentes,
Mariana Martinez, Raquel Zubia

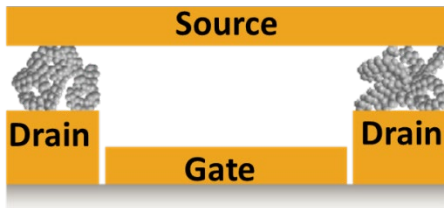
Professors: David Zubia, Dr. Jose Mireles (UACJ Mexico)



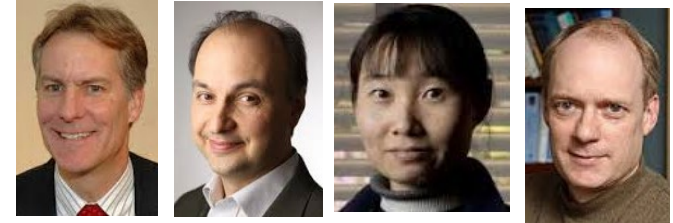
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NSF Virtual Site Visit
February 8, 2019

Theme II Projects & PIs

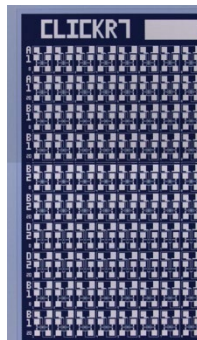
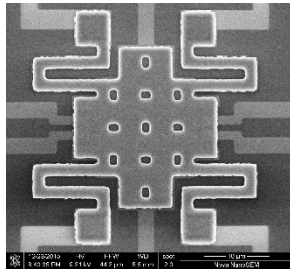


- Squitch [Lang, Bulović, Kong, Swager]
 - Compressible molecules
 - Multi-terminal design

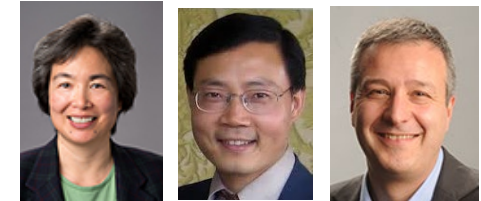
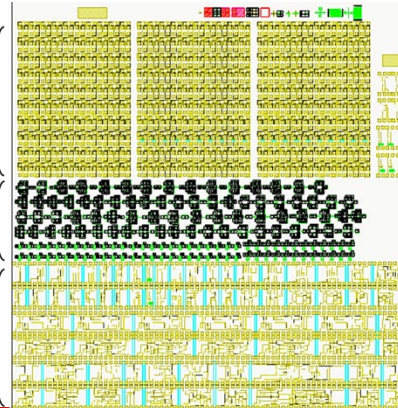


- Low-Voltage Relay Integrated Circuits [Liu, Wu, Stojanović]

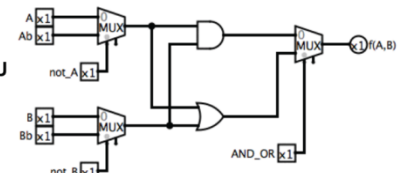
- Sub-100 mV circuit demonstration



Vertically actuated relays
Laterally actuated relays
Relay ICs

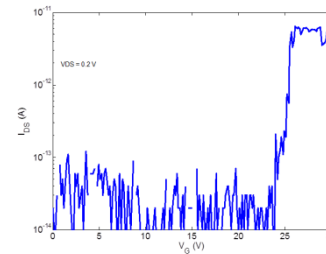
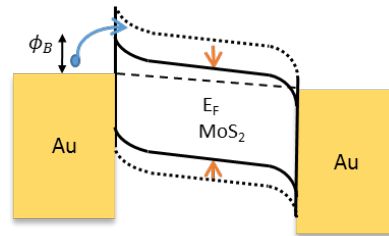
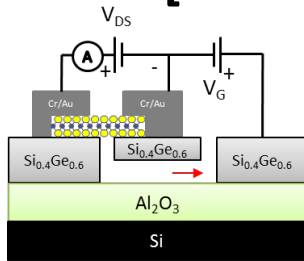


1-bit ALU



- Stritch [Zubia]

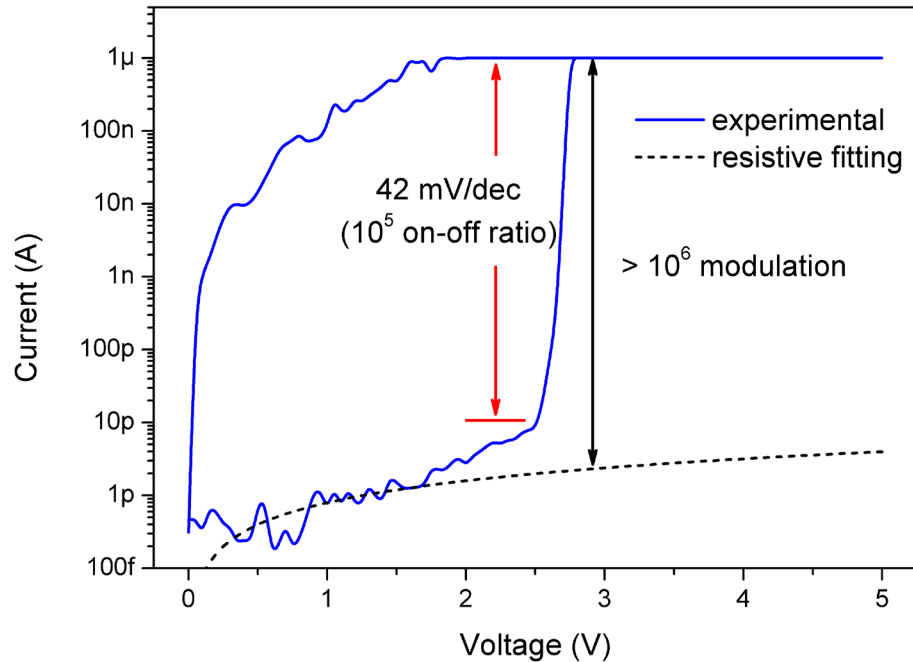
- Low-voltage actuator design for inducing strain in 2-D materials



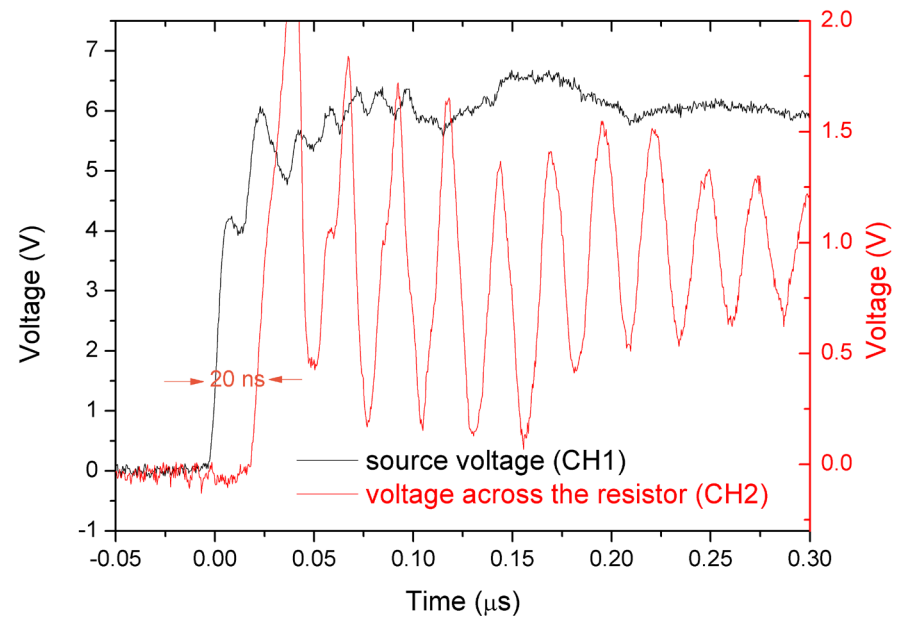
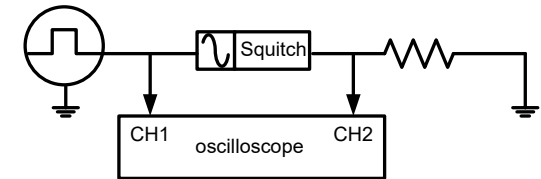
Squitch Update

1. Two-terminal Squitches have been experimentally demonstrated with

- low actuation voltage ($\sim 2V$)
- large on-off ratio ($>10^5$)
- small subthreshold slope (~ 40 mV/dec)
- negligible OFF-state leakage (< 1 pA)
- short switching delay (~ 15 ns, excluding delay from measurement circuit)



Typical IV curve of Squitch based on PEG-thiol molecules



Experimental result of dynamics of squitch

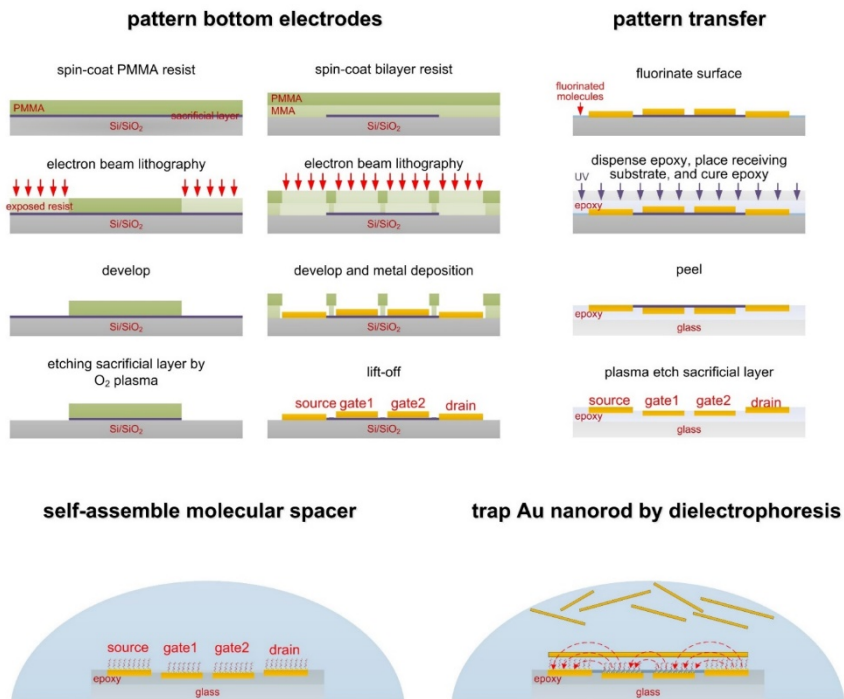


Squitch Update (continued)

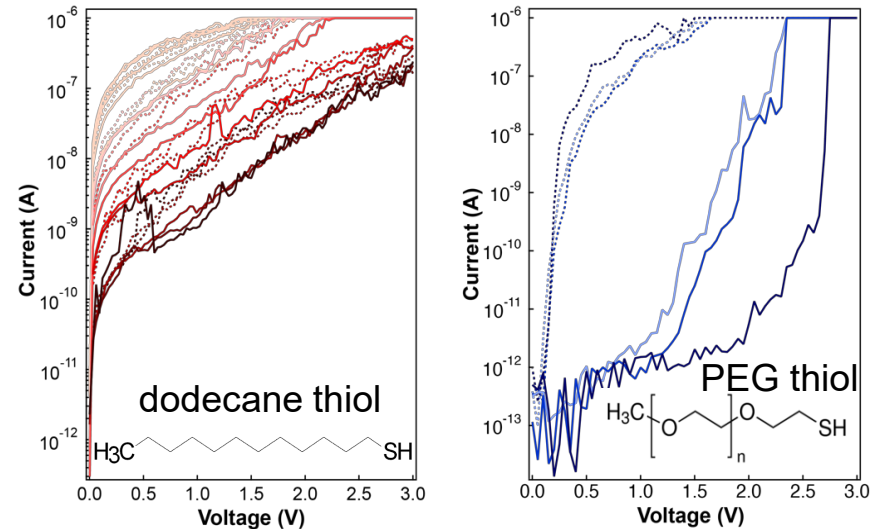
2. nanofabrication process has been improved for a higher throughput (scalable) and a better yield (~40%, limited by DEP trapping)

3. The significant role of molecules has been illuminated

- behavior of squitches can be designed by engineering the molecules
- squitch can perform as a useful metrology platform to study the mechanics of molecules



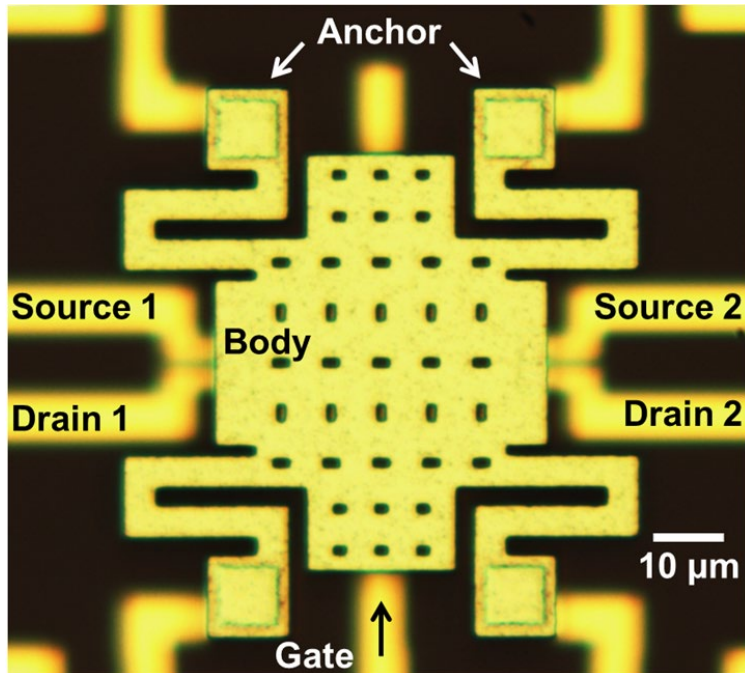
Scalable nanofabrication process of squitches



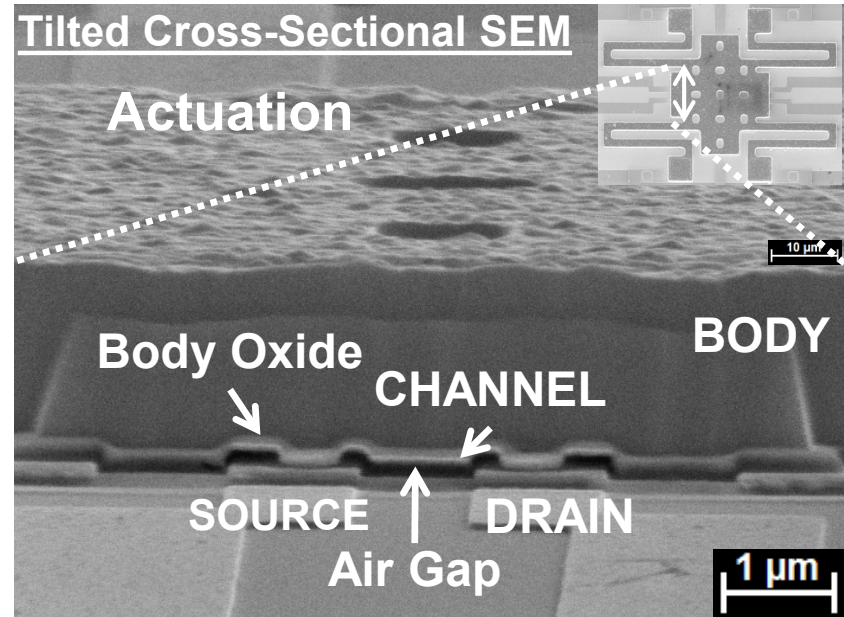
IV curves of squitches based on dodecane-thiol molecules and PEG-thiol molecules over cycles of switching

Body-Biased Relay Structure and Operation

Plan-View Microscopic Image

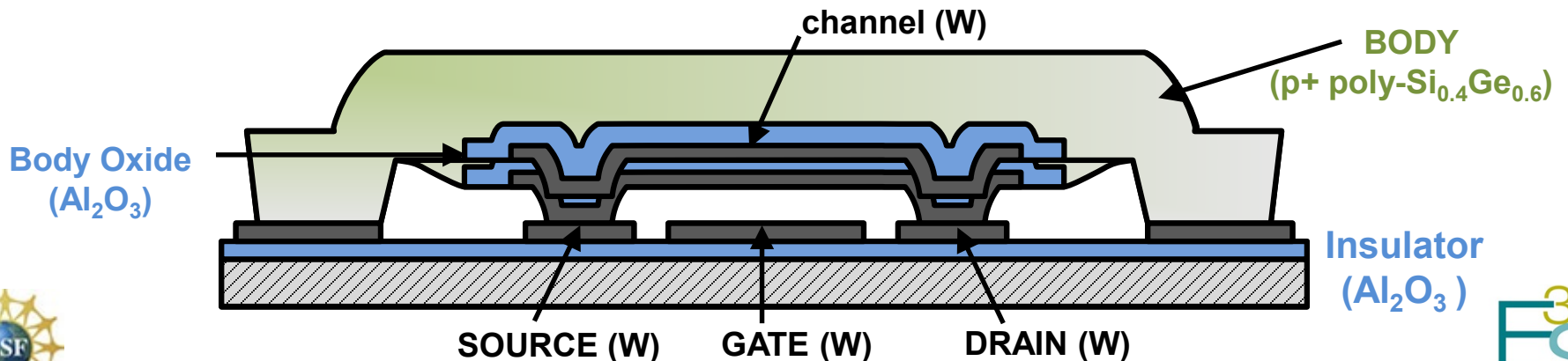


Plan-View SEM



I-R. Chen *et al.* (UCB), *Transducers* 2013

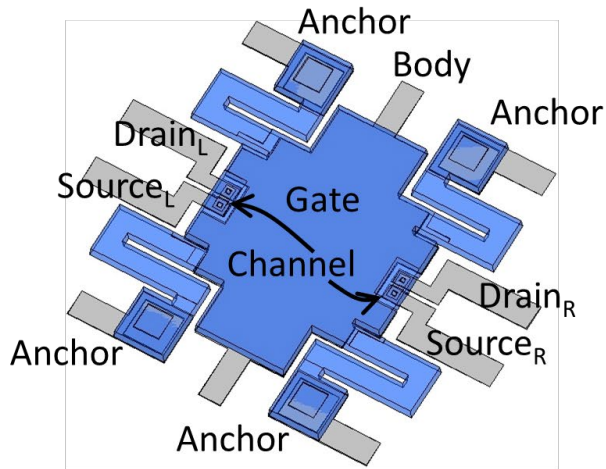
Schematic Cross-section



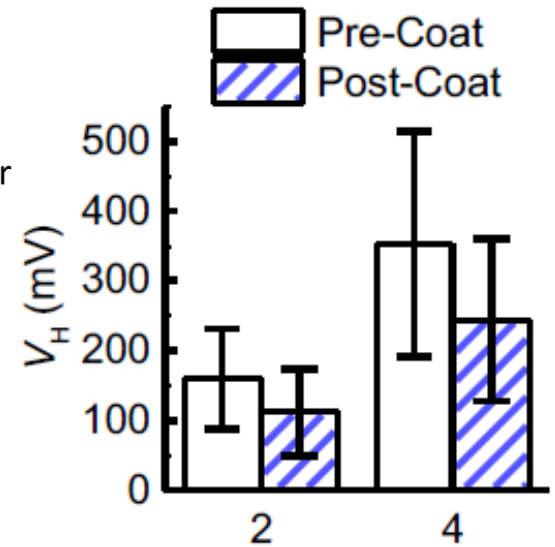
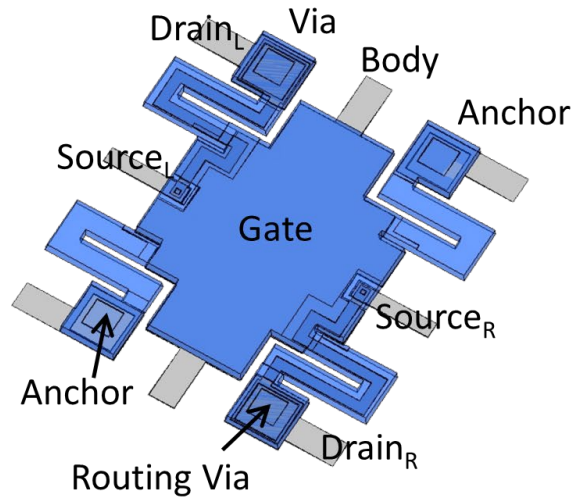
Improved Body-Biased Relay Design

Z. A. Ye *et al.*, presented at the 2018 IEEE International Electron Devices Meeting

4-Contact Design



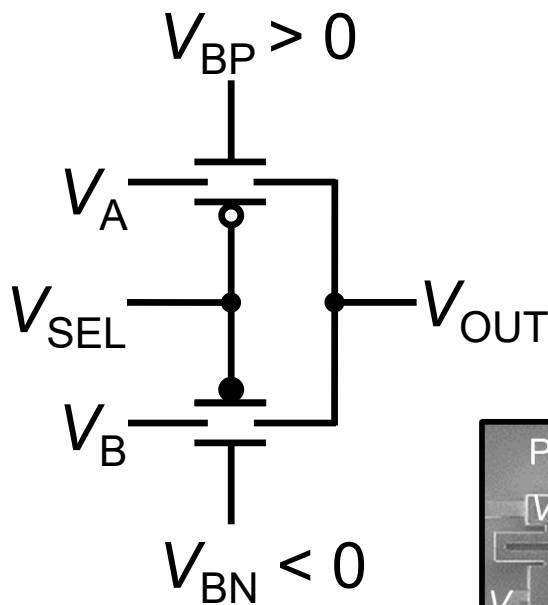
2-Contact Design



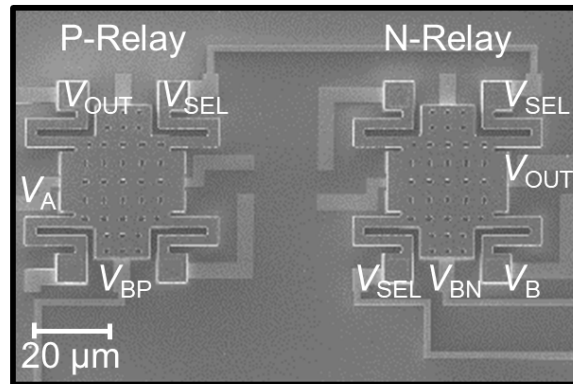
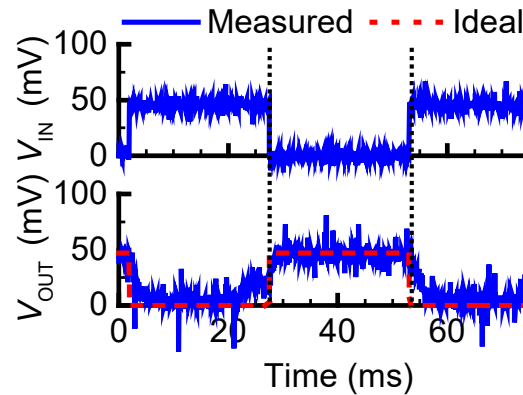
50 mV Relay Integrated Circuit Demos

Z. A. Ye *et al.*, presented at the 2018 IEEE International Electron Devices Meeting

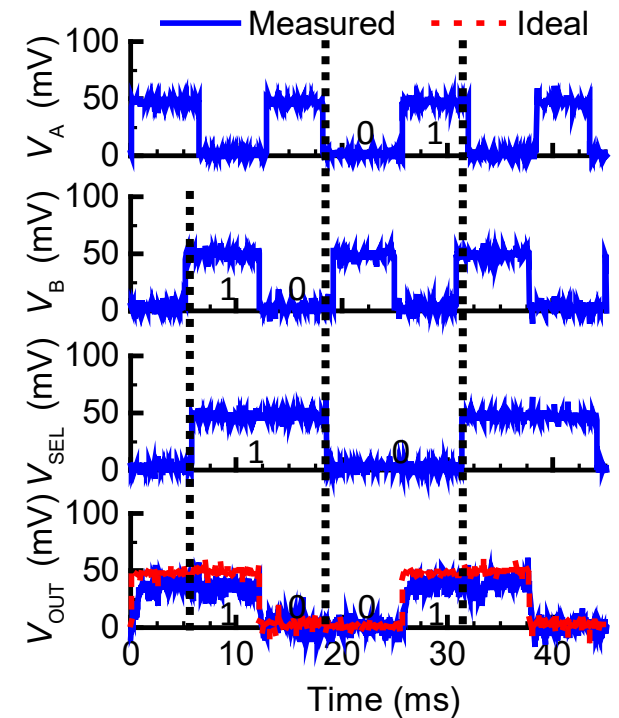
Circuit Diagram



Inverter Waveforms



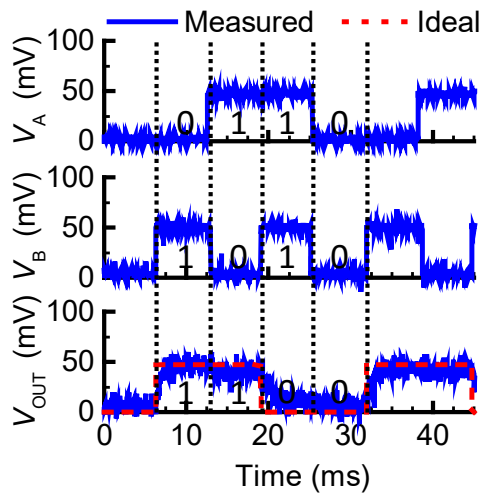
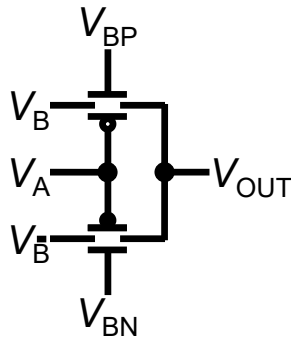
2:1 MUX Waveforms



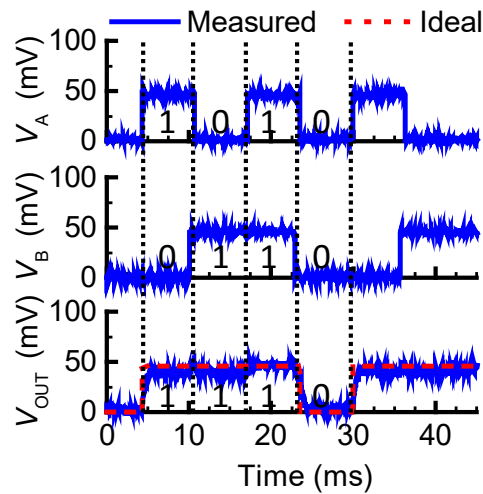
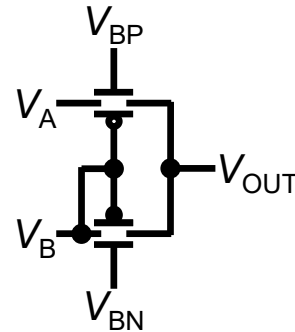
50 mV Relay Logic Gate Demos

Z. A. Ye *et al.*, presented at the 2018 IEEE International Electron Devices Meeting

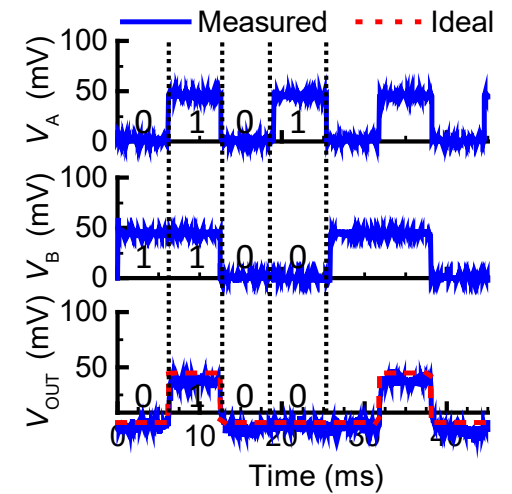
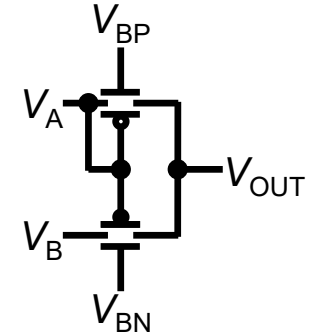
XOR GATE



OR GATE



AND GATE



2/8/2019

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2019 NSF STC Virtual Site Visit

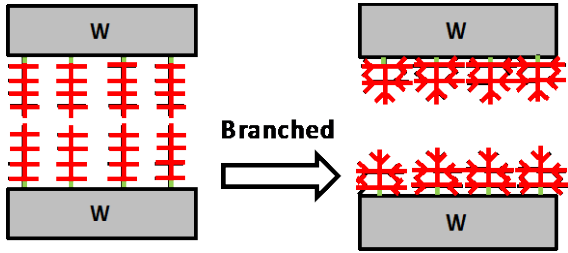
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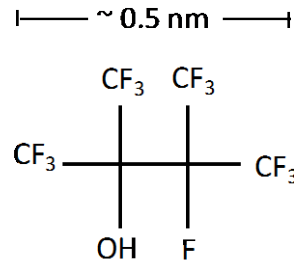


Center for Energy Efficient Electronics Science

Self-Assembled Molecular (SAM) Coatings

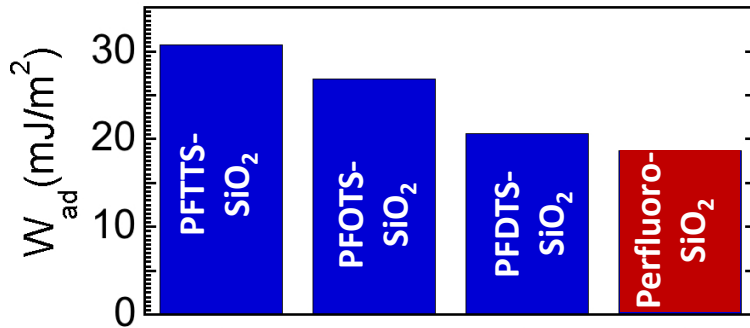


Perfluoro(2,3-dimethylbutan-2-ol)

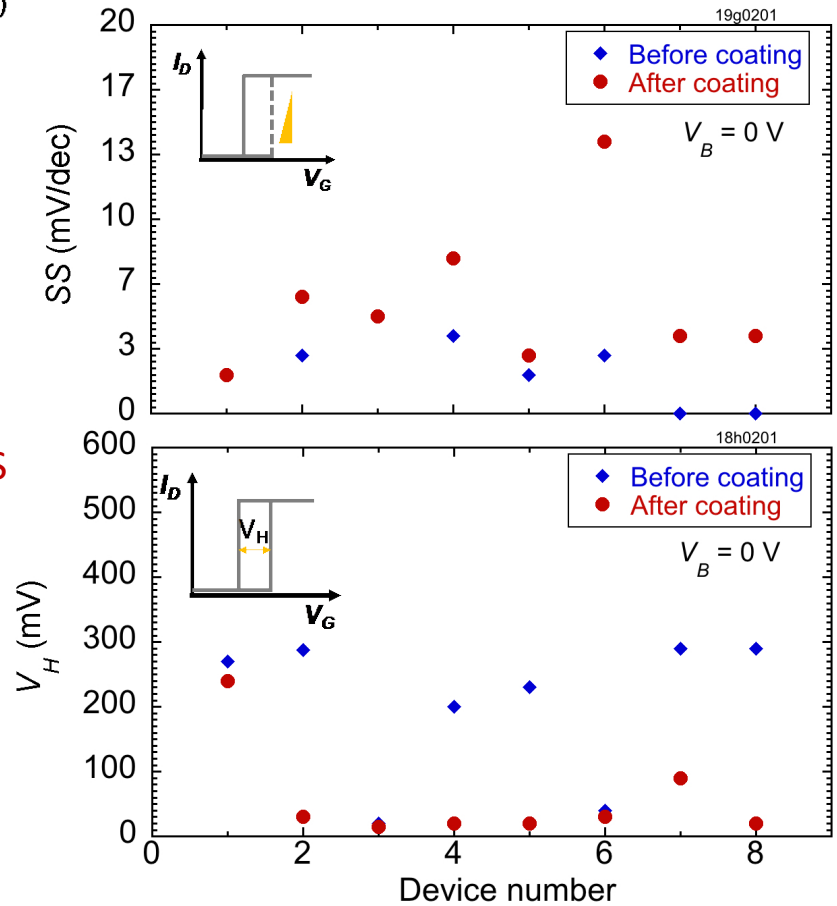


Perfluoro has ~24 F atoms/nm vs. ~10 F atoms/nm in PFOTES

Motivation: reducing adhesion (more F atoms) without sacrificing electrical conduction (short molecule).

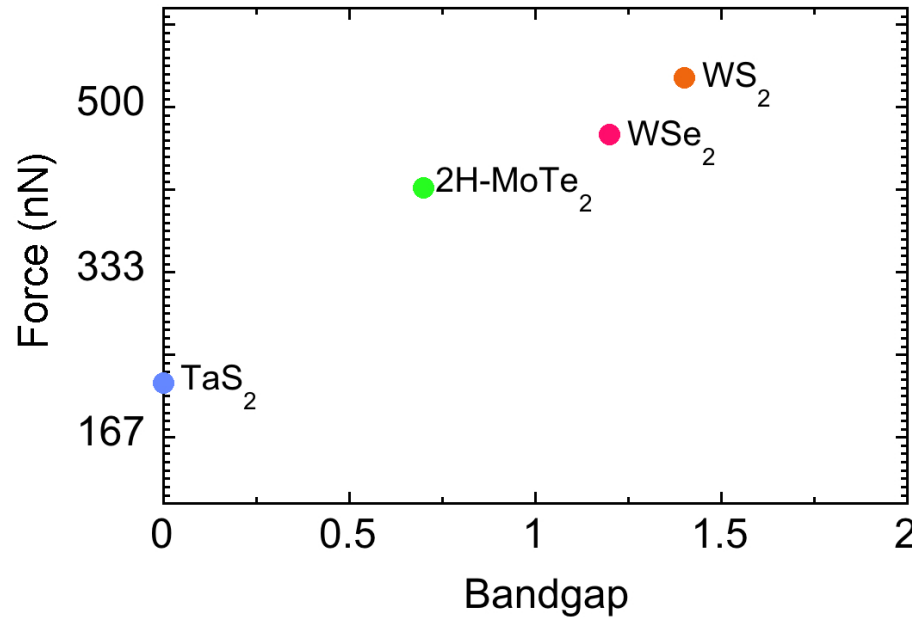
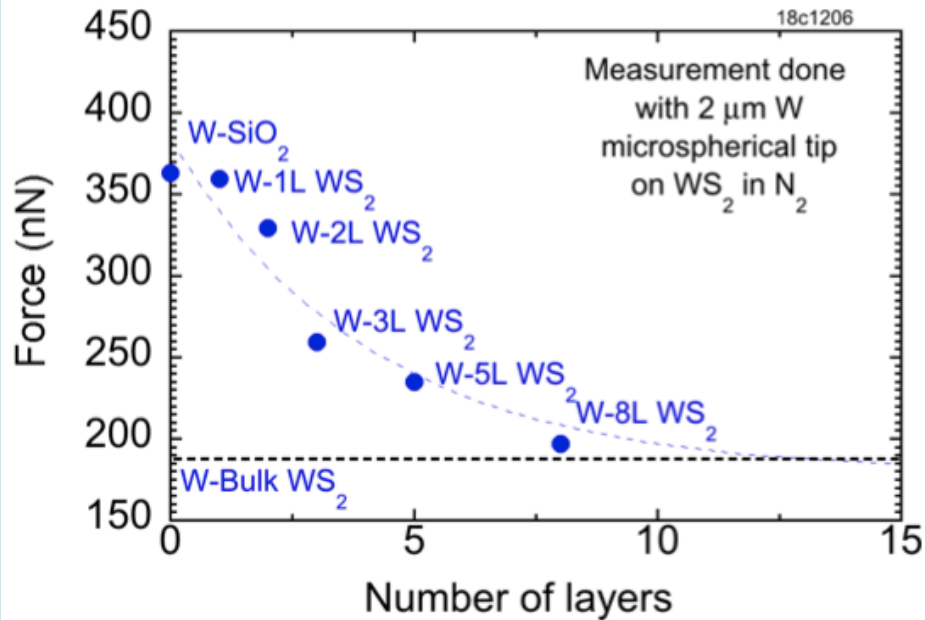


Lower adhesion energy with Perfluoro coating



Reduced hysteresis while maintaining low subthreshold swing

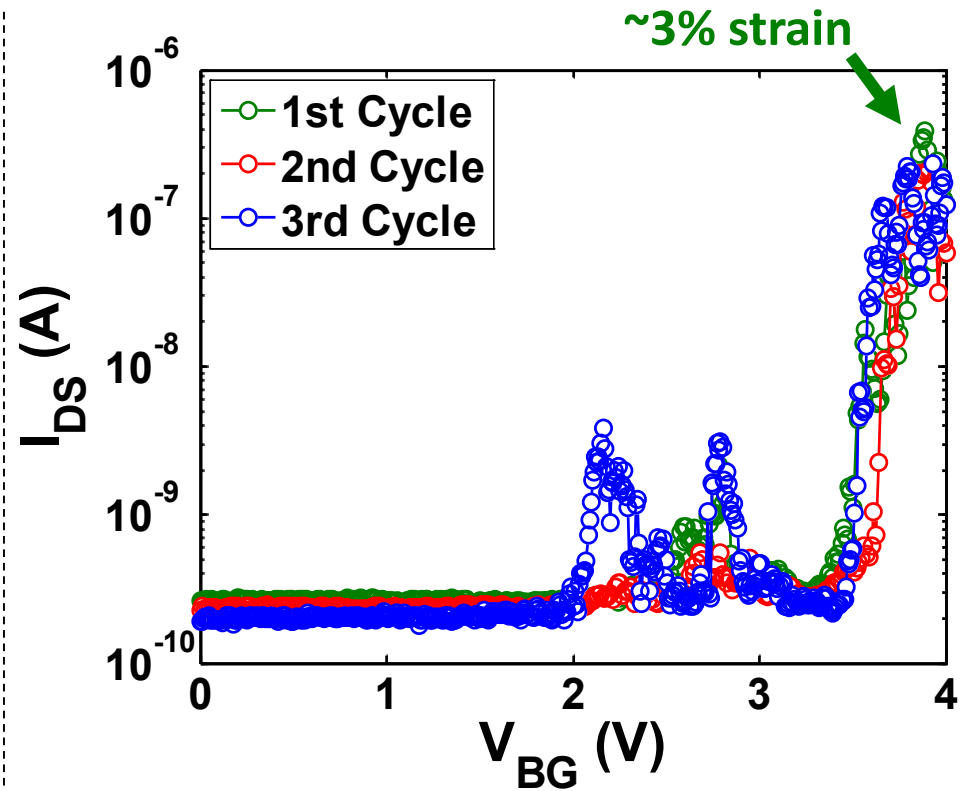
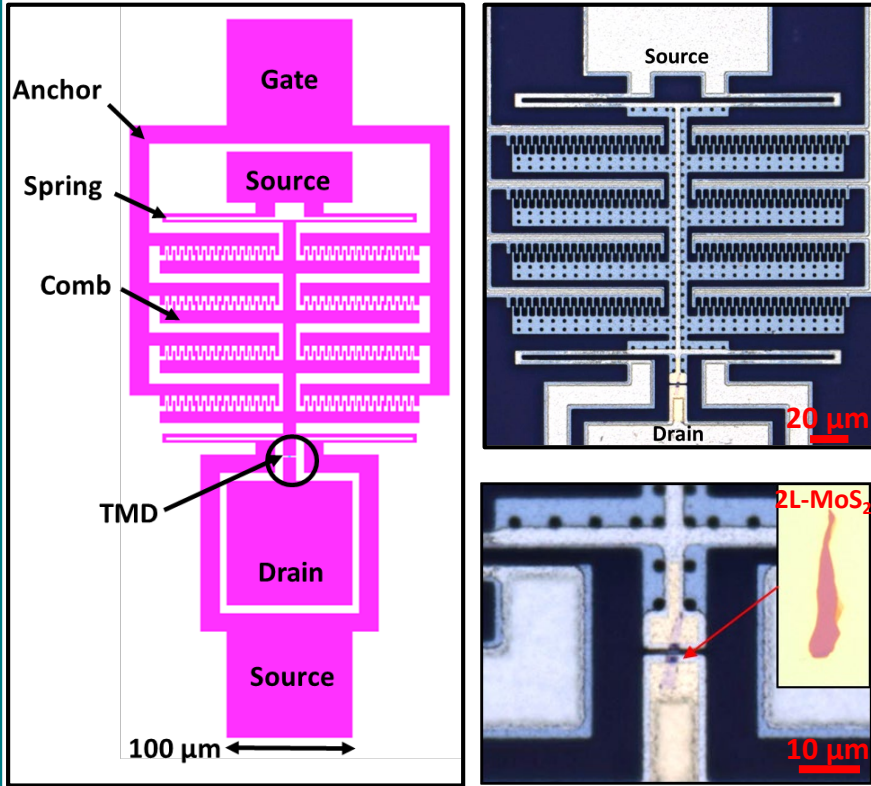
Transition-Metal Dichalcogenide Adhesive Force



Adhesive force decreases with bandgap of bulk TMD: as bandgap decreases, electron density increases, and the screening of adhesive force by electrons becomes more pronounced.

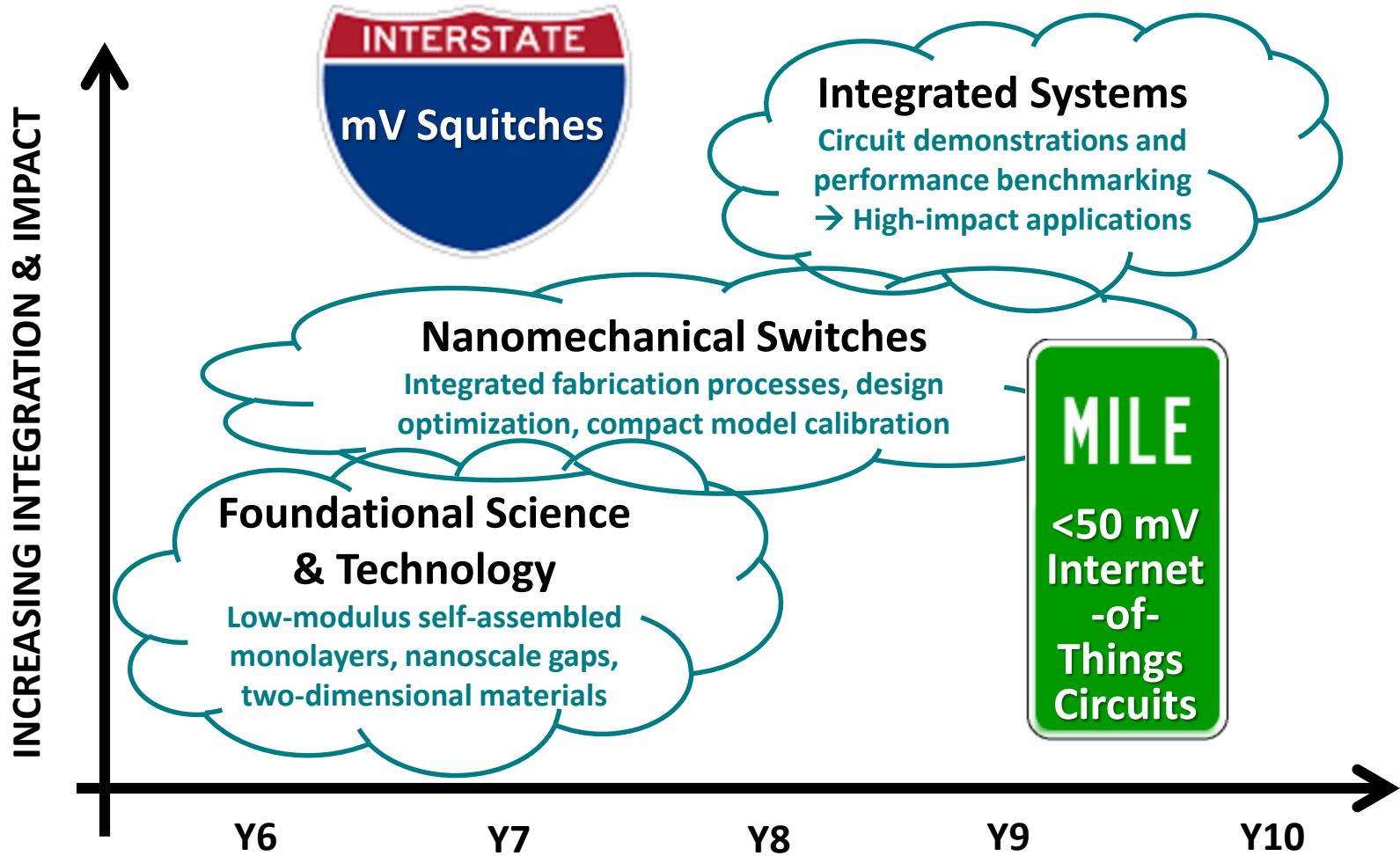


Stritch Update



- Comb-drive actuator was designed and fabricated @UCB using poly-Si_{0.35}Ge_{0.65}
- Strain-induced conductivity modulation in bi-layer MoS₂ flake demonstrated
- **$\sim 3000x$ increase in conductivity measured over multiple cycles!**

Theme II (Nanomechanics) Roadmap



Theme II Legacy

- **milliVolt nanomechanical digital computation**
across a wide range of operating conditions
 - **Stritch**
 - **Squitch**
 - **BEOL switches (reconfigurable interconnects)**
- **E-book**

